

# P-Channel Power MOSFET

-20V, -6.5A, 26mΩ

#### **FEATURES**

- Fast switching
- Suitable for -1.8V Gate Drive Applications
- Pb-free plating
- RoHS compliant
- Halogen-free mold compound

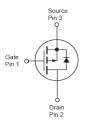
KEY PERFORMANCE PARAMETERS				
PARAMETER		VALUE	UNIT	
V <sub>DS</sub>		-20	V	
I <sub>D</sub>		-6.5	Α	
R <sub>DS(on)</sub> (max)	V <sub>GS</sub> = -4.5V	26		
	$V_{GS} = -2.5V$	32	mΩ	
	$V_{GS} = -1.8V$	40		
$Q_{g}$		19.5	nC	

#### **APPLICATION**

- Battery Pack
- Portable Devices







#### Note:

- 1. MSL 1 (Moisture Sensitivity Level) for SOT-26 per J-STD-020
- 2. MSL 3 (Moisture Sensitivity Level) for SOT-23 per J-STD-020

ABSOLUTE MAXIMUM RATINGS (T <sub>C</sub> = 25°C unless otherwise noted)				
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-Source Voltage		V <sub>DS</sub>	-20	V
Gate-Source Voltage		V <sub>GS</sub>	±10	V
Continuous Drain Current	$T_C = 25^{\circ}C$		-6.5	^
	T <sub>C</sub> = 100°C	I <sub>D</sub>	-4.1	A
Pulsed Drain Current (Note 1)		I <sub>DM</sub>	-26	А
Total Power Dissipation	T <sub>C</sub> = 25°C	P <sub>DTOT</sub>	1.56	W
Operating Junction Temperature		T <sub>J</sub>	150	°C
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	- 55 to +150	°C

THERMAL PERFORMANCE				
PARAMETER	SYMBOL	LIMIT	TINU	
Junction to Ambient Thermal Resistance	R <sub>OJA</sub>	80	°C/W	

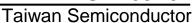
**Notes:**  $R_{\Theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistances.  $R_{\Theta JC}$  is guaranteed by design while  $R_{\Theta CA}$  is determined by the user's board design.  $R_{\Theta JA}$  is shown for single device operation on FR-4 PCB in still air.



<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>A</sub> = 25°C unless otherwise noted)						
PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Static (Note 2)						•
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = -250\mu A$	BV <sub>DSS</sub>	-20			V
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	V <sub>GS(TH)</sub>	-0.3	-0.6	-1.0	V
Gate Body Leakage	$V_{GS} = \pm 10V, V_{DS} = 0V$	I <sub>GSS</sub>			±100	nA
Zero Gate Voltage Drain Current	$V_{DS} = -20V, V_{GS} = 0V$		-		-1	μА
	$V_{DS} = -16V, T_J = 125^{\circ}C$	I <sub>DSS</sub>			-10	
Drain-Source On-State Resistance	$V_{GS} = -4.5V, I_D = -5A$		-	21	26	mΩ
	$V_{GS} = -2.5V, I_D = -4A$	$R_{DS(on)}$	-	26	32	
	$V_{GS} = -1.8V, I_D = -3A$		-	32	40	
Forward Transconductance	$V_{DS} = -10V, I_{S} = -5A$	g <sub>fs</sub>		15		S
Dynamic (Note 3)						
Total Gate Charge		$Q_g$		19.5		nC
Gate-Source Charge	$V_{DS} = -10V, I_D = -5A,$ $V_{GS} = -4.5V$	$Q_{gs}$		2		
Gate-Drain Charge		$Q_gd$		3.6		
Input Capacitance	.,	C <sub>iss</sub>		1670		
Output Capacitance	$V_{DS} = -15V, V_{GS} = 0V,$	C <sub>oss</sub>		220		pF
Reverse Transfer Capacitance	F = 1.0MHz	C <sub>rss</sub>		120		
Switching						
Turn-On Delay Time		t <sub>d(on)</sub>		10.4		
Turn-On Rise Time	$V_{DD} = -10V, I_{D} = -1A,$ $V_{GS} = -4.5V,$ $R_{GEN} = 25\Omega$	t <sub>r</sub>		37.5		
Turn-Off Delay Time		t <sub>d(off)</sub>		89.1		ns
Turn-Off Fall Time	- NGEN -2312	t <sub>f</sub>		24.6		
Source-Drain Diode						
Forward Voltage	$V_{GS} = 0V, I_{S} = -1A$	$V_{SD}$			-1	V
Continuous Forward Current	Integral reverse diode	I <sub>S</sub>			-6.5	Α
Pulse Forward Current	in the MOSFET	I <sub>SM</sub>			-26	Α

#### Notes:

- 1. Pulse width limited by safe operating area
- 2. Pulse test: PW  $\leq$  300 $\mu$ s, duty cycle  $\leq$  2%
- 3. Switching time is essentially independent of operating temperature.





# **ORDERING INFORMATION**

ORDERING CODE	PACKAGE	PACKING
TSM260P02CX RFG	SOT-23	3,000pcs / 7" Reel
TSM260P02CX6 RFG	SOT-26	3,000pcs / 7" Reel

#### Note:

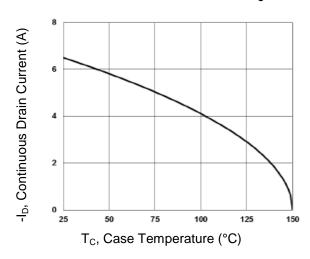
- 1. Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- 2. Halogen-free according to IEC 61249-2-21 definition



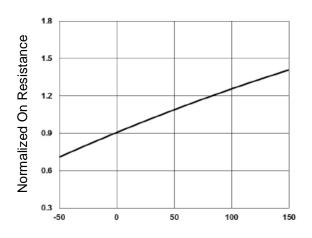
## **CHARACTERISTICS CURVES**

(T<sub>C</sub> = 25°C unless otherwise noted)

#### Continuous Drain Current vs. T<sub>C</sub>

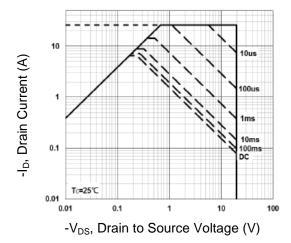


#### **On-Resistance vs. Junction Temperature**

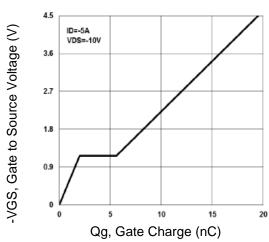


T<sub>J</sub>, Junction Temperature (°C)

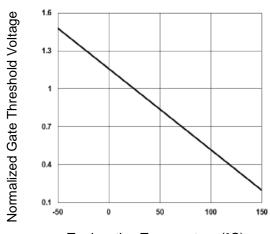
#### **Maximum Safe Operating Area**



### **Gate Charge**

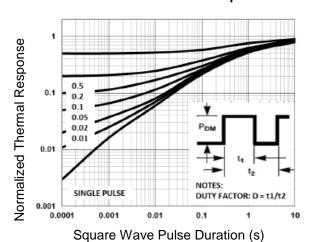


## Threshold Voltage vs. Junction Temperature



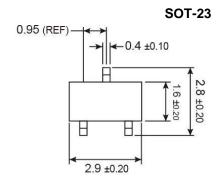
T<sub>J</sub>, Junction Temperature (°C)

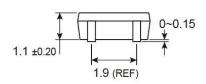
#### **Normalized Thermal Transient Impedance Curve**

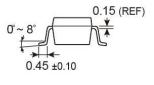




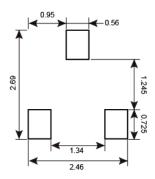
# PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)







# SUGGESTED PAD LAYOUT (Unit: Millimeters)



## **MARKING DIAGRAM**



26 = Device Code

Y = Year Code

**M** = Month Code for Halogen Free Product

T =Jun

O =Jan **P** =Feb **Q** =Mar  $\mathbf{R}$  =Apr S =May **U** =Jul

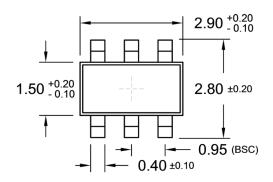
**V** =Aug W =Sep X =Oct Y =Nov **Z** =Dec

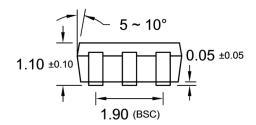
= Lot Code

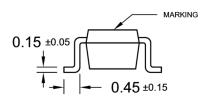


## PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

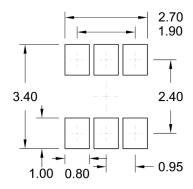
#### **SOT-26**







## SUGGESTED PAD LAYOUT (Unit: Millimeters)



## **MARKING DIAGRAM**



26 = Device Code

Y = Year Code

**M** = Month Code for Halogen Free Product

O =Jan P =Feb Q =Mar R =Apr

S =May T =Jun U =Jul V =Aug

W =Sep X =Oct Y =Nov Z =Dec

L = Lot Code (1~9, A~Z)





# **Notice**

Specifications of the products displayed herein are subject to change without notice. TSC or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, to any intellectual property rights is granted by this document. Except as provided in TSC's terms and conditions of sale for such products, TSC assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of TSC products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify TSC for any damages resulting from such improper use or sale.